

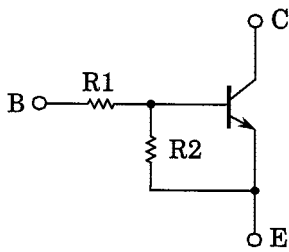
TOSHIBA Transistor Silicon NPN Epitaxial Type (PCT Process)

## RN1901,RN1902,RN1903 RN1904,RN1905,RN1906

Switching, Inverter Circuit, Interface Circuit  
And Driver Circuit Applications

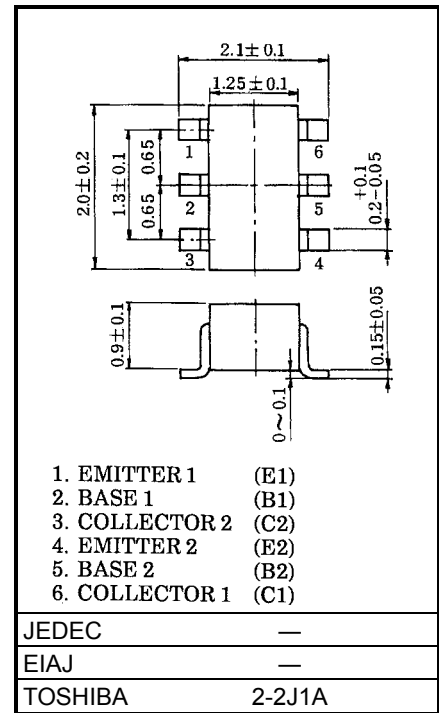
- Including two devices in US6 (ultra super mini type with 6 leads)
- With built-in bias resistors
- Simplify circuit design
- Reduce a quantity of parts and manufacturing process
- Complementary to RN2901~RN2906

### Equivalent Circuit and Bias Resistor Values



Type No.	R1 (kΩ)	R2 (kΩ)
RN1901	4.7	4.7
RN1902	10	10
RN1903	22	22
RN1904	47	47
RN1905	2.2	47
RN1906	4.7	47

Unit: mm



1. EMITTER 1 (E1)
2. BASE 1 (B1)
3. COLLECTOR 2 (C2)
4. EMITTER 2 (E2)
5. BASE 2 (B2)
6. COLLECTOR 1 (C1)

JEDEC	—
EIAJ	—
TOSHIBA	2-2J1A

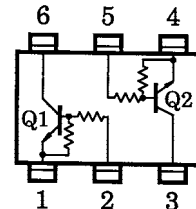
Weight: 6.8mg

### Equivalent Circuit (Top View)

### Maximum Ratings (Ta = 25°C) (Q1, Q2 Common)

Characteristic	Symbol	Rating	Unit
Collector-base voltage	$V_{CB0}$	50	V
Collector-emitter voltage	$V_{CEO}$	50	V
Emitter-base voltage	$V_{EBO}$	10	V
		5	
Collector current	$I_C$	100	mA
Collector power dissipation	$P_C^*$	200	mW
Junction temperature	$T_j$	150	°C
Storage temperature range	$T_{stg}$	-55~150	°C

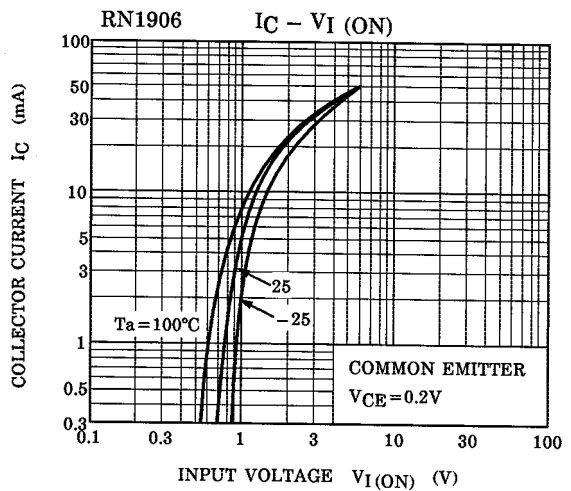
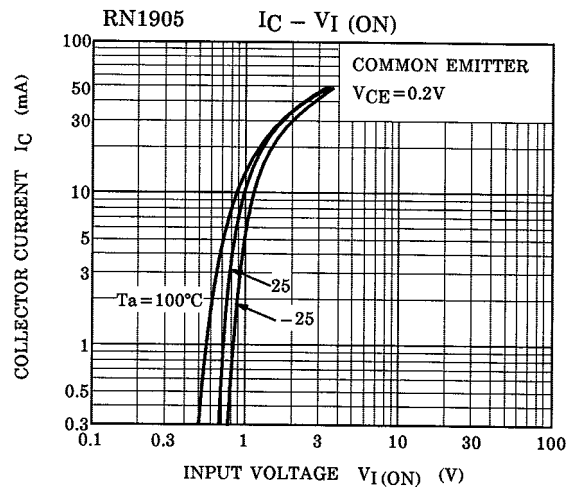
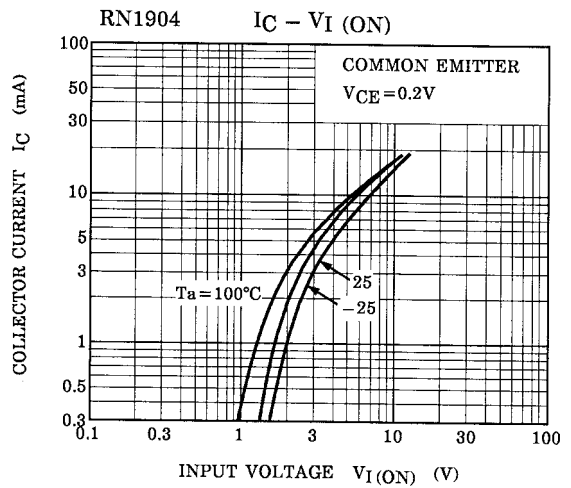
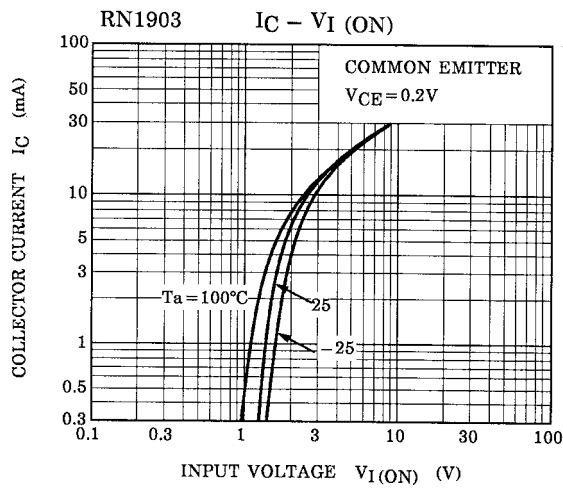
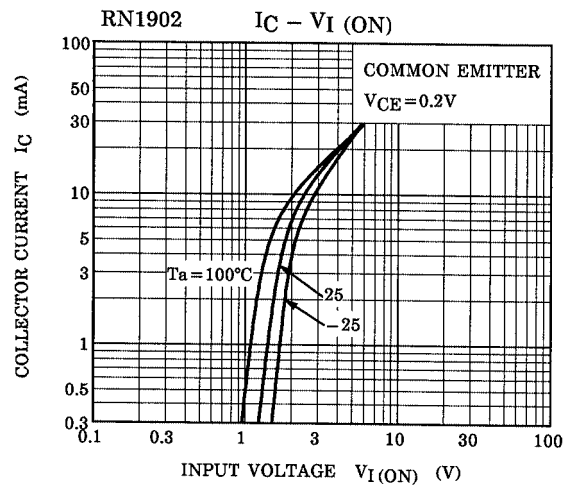
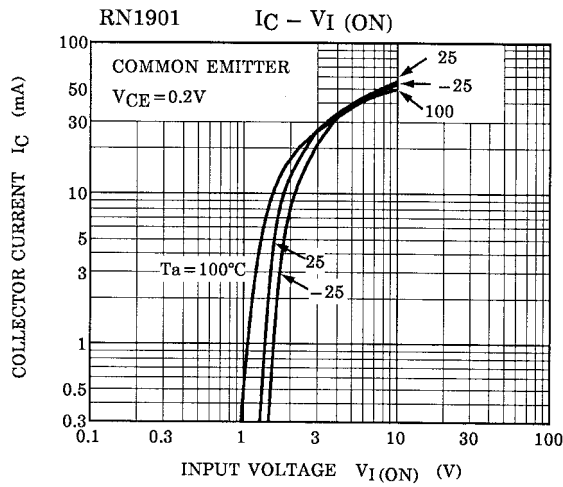
\*: Total rating



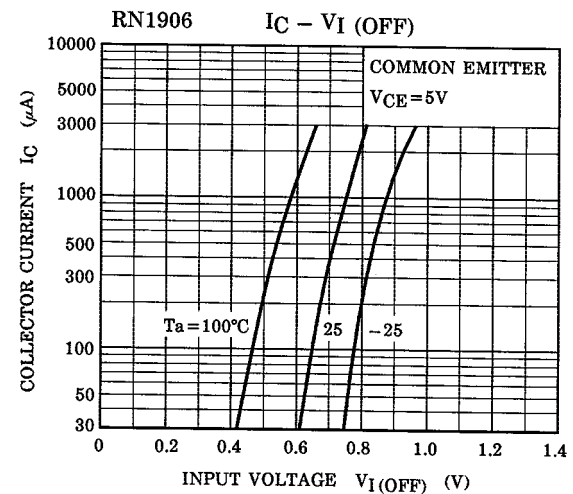
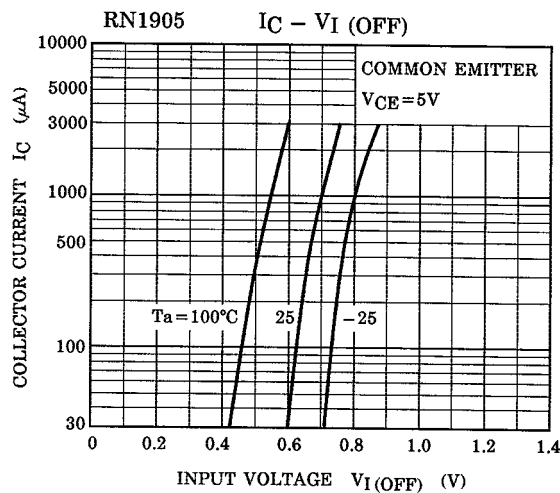
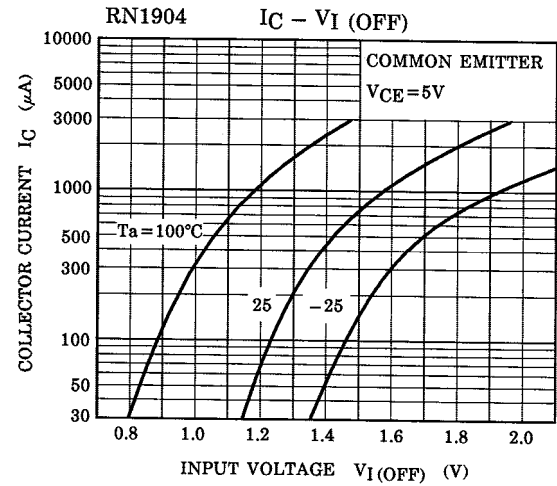
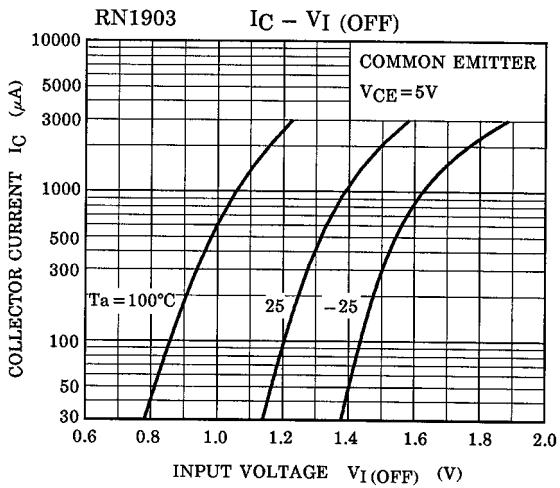
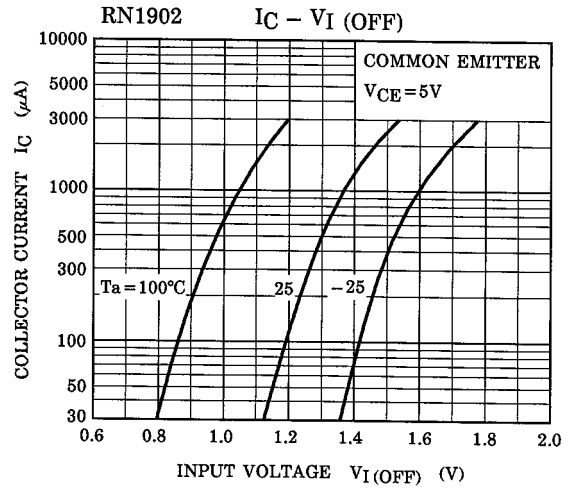
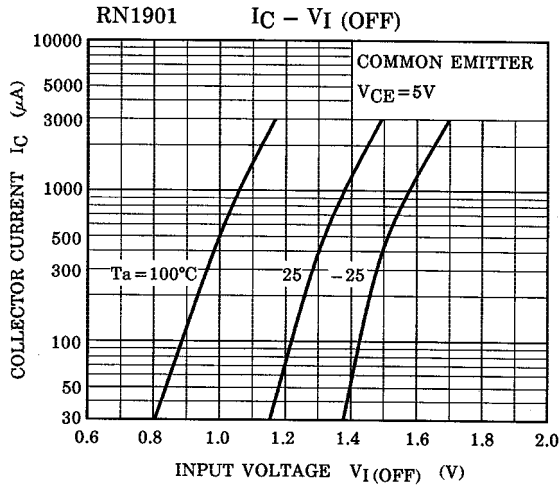
## Electrical Characteristics (Ta = 25°C) (Q1, Q2 Common)

Characteristic		Symbol	Test Circuit	Test Condition	Min	Typ.	Max	Unit
Collector cut-off current	RN1901~1906	$I_{CBO}$	—	$V_{CB} = 50V, I_E = 0$	—	—	100	nA
		$I_{CEO}$	—	$V_{CE} = 50V, I_B = 0$	—	—	500	
Emitter cut-off current	RN1901	$I_{EBO}$	—	$V_{EB} = 10V, I_C = 0$	0.82	—	1.52	mA
	RN1902		—		0.38	—	0.71	
	RN1903		—		0.17	—	0.33	
	RN1904		—	0.082	—	0.15		
	RN1905		—	$V_{EB} = 5V, I_C = 0$	0.078	—	0.145	
	RN1906		—		0.074	—	0.138	
DC current gain	RN1901	$h_{FE}$	—	$V_{CE} = 5V, I_C = 10mA$	30	—	—	—
	RN1902		—		50	—	—	
	RN1903		—		70	—	—	
	RN1904		—		80	—	—	
	RN1905		—		80	—	—	
	RN1906		—		80	—	—	
Collector-emitter saturation voltage	RN1901~1906	$V_{CE(sat)}$	—	$I_C = 5mA, I_B = 0.25mA$	—	0.1	0.3	V
Input voltage (ON)	RN1901	$V_{I(ON)}$	—	$V_{CE} = 0.2V, I_C = 5mA$	1.1	—	2.0	V
	RN1902		—		1.2	—	2.4	
	RN1903		—		1.3	—	3.0	
	RN1904		—		1.5	—	5.0	
	RN1905		—		0.6	—	1.1	
	RN1906		—		0.7	—	1.3	
Input voltage (OFF)	RN1901~1904	$V_{I(OFF)}$	—	$V_{CE} = 5V, I_C = 0.1mA$	1.0	—	1.5	V
	RN1905, 1906		—		0.5	—	0.8	
Translation frequency	RN1901~1906	$f_T$	—	$V_{CE} = 10V, I_C = 5mA$	—	250	—	MHz
Collector output capacitance	RN1901~1906	$C_{ob}$	—	$V_{CB} = 10V, I_E = 0, f = 1MHz$	—	3	6	pF
Input resistor	RN1901	R1	—	—	3.29	4.7	6.11	kΩ
	RN1902		—		7	10	13	
	RN1903		—		15.4	22	28.6	
	RN1904		—		32.9	47	61.1	
	RN1905		—		1.54	2.2	2.86	
	RN1906		—		3.29	4.7	6.11	
Resistor ratio	RN1901~1904	R1/R2	—	—	0.9	1.0	1.1	—
	RN1905		—		0.0421	0.0468	0.0515	
	RN1906		—		0.09	0.1	0.11	

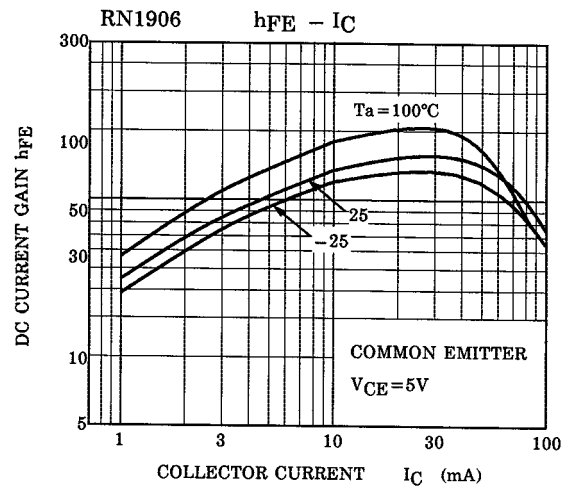
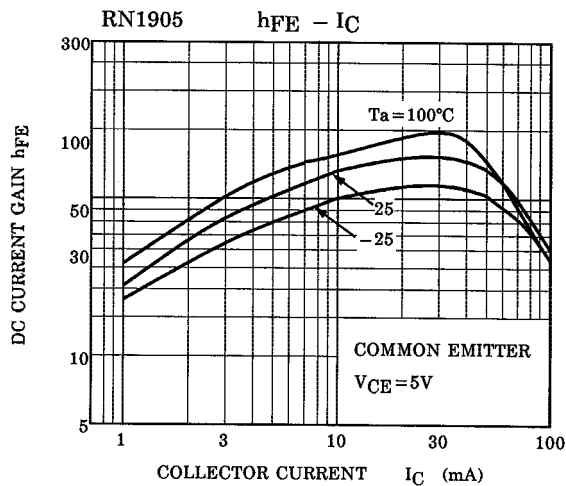
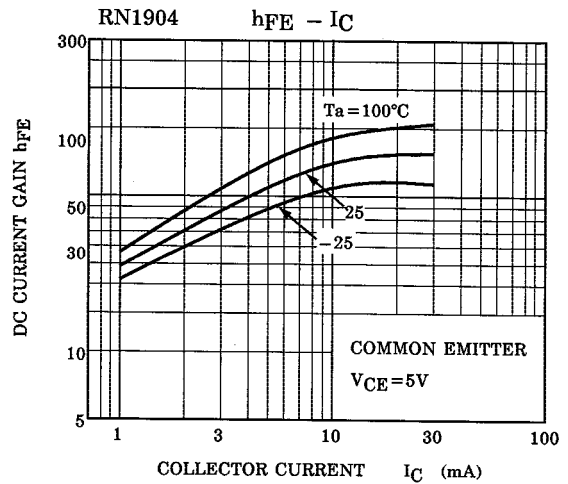
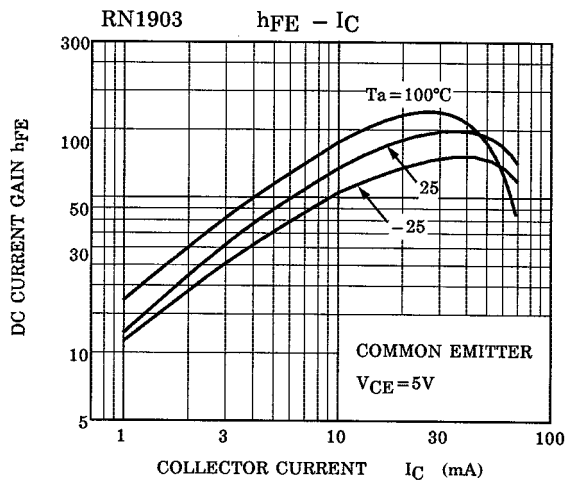
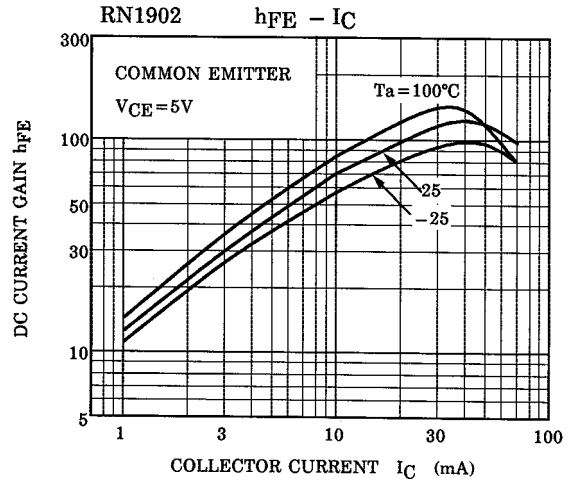
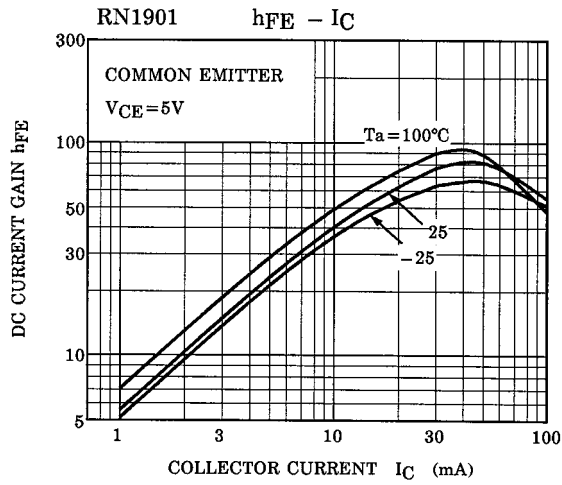
(Q1, Q2 Common)

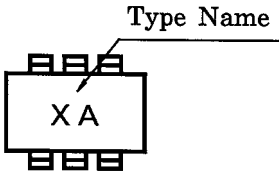
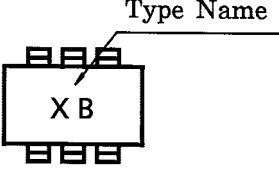
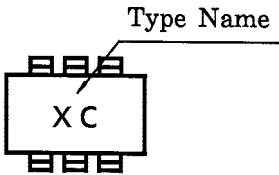
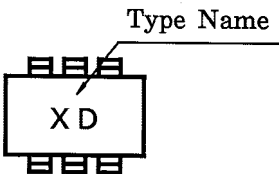
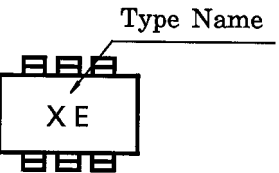
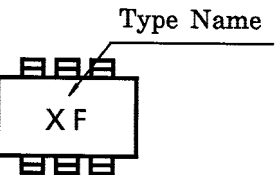


(Q1, Q2 Common)



(Q1, Q2 Common)



Type Name	Marking
RN1901	
RN1902	
RN1903	
RN1904	
RN1905	
RN1906	

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